

# HMC344LP3 / 344LP3E

# GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 8.0 GHz



## Typical Applications

This switch is suitable for usage in DC - 8.0 GHz 50-Ohm or 75-Ohm systems:

- Broadband
- Fiber Optics
- Switched Filter Banks
- Wireless below 8 GHz

#### **Features**

Broadband Performance: DC - 8.0 GHz

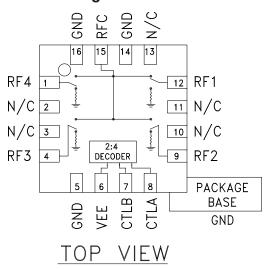
High Isolation: 40 dB@ 6 GHz

Low Insertion Loss: 1.8 dB@ 6 GHz

Integrated 2:4 TTL Decoder

LP3 SMT Package

## **Functional Diagram**



## **General Description**

The HMC344LP3 & HMC344LP3E are broadband non-reflective GaAs MESFET SP4T switches in low cost leadless surface mount packages. Covering DC to 8 GHz, this switch offers high isolation and low insertion loss and extends the frequency coverage of Hittite's SP4T switch product line. This switch also includes an on board binary decoder circuit which reduces the required logic control lines to two. The switch operates using a negative control voltage of 0/-5V, and requires a fixed bias of -5V.

# Electrical Specifications, $T_A = +25^{\circ}$ C, With 0/-5V Control, 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 6.0 GHz DC - 8.0 GHz		1.6 1.8 2.1	2.0 2.2 2.5	dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	43 36 34 31	48 41 40 36		dB dB dB dB
Return Loss	"On State"	DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz DC - 8.0 GHz	12 9 8 5	15 12 11 8		dB dB dB dB
Return Loss	"Off State"	DC - 8.0 GHz	7	10		dB
Input Power for 1 dB Compression		0.5 - 8.0 GHz	17	21		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone)		0.5 - 8.0 GHz	37	40		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)	_	DC - 8.0 GHz		35 150		ns ns

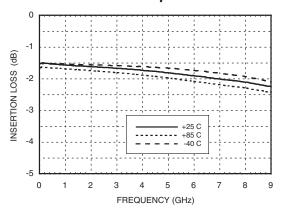


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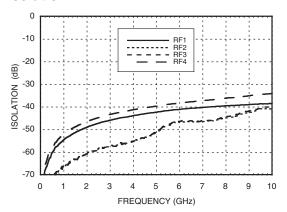
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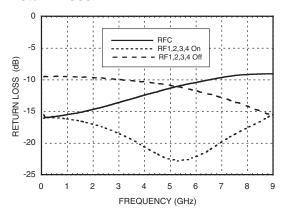
#### Insertion Loss vs. Temperature



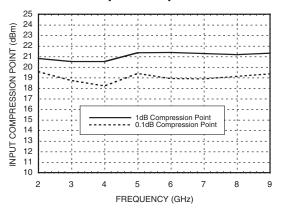
#### Isolation



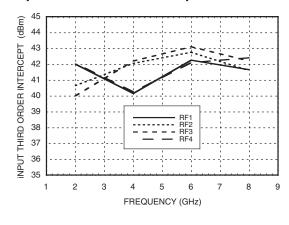
#### **Return Loss**



## 0.1 and 1 dB Input Compression Point



#### Input Third Order Intercept Point



## Bias Voltage & Current

Vee Range = -5.0 Vdc ± 10%		
Vee (Vdc)	lee (Typ.) (mA)	lee (Max.) (mA)
-5.0	3.0	6.0

## **Control Voltages**

State	Bias Condition	
Low	-3V to 0 Vdc @ 60 uA Typical	
High	-5 to -4.2 Vdc @ 5 uA Typical	

<sup>\*</sup> Isolation is recorded above insertion loss & measured at output of switch.



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## **Absolute Maximum Ratings**

Bias Voltage Range (Vee)	-7.0 Vdc
Control Voltage Range (A & B)	Vee -0.5V to +1.0 Vdc
Channel Temperature	150 °C
Thermal Resistance (Insertion Loss Path)	143 °C/W
Thermal Resistance (Terminated Path)	1,030 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power	+24 dBm
ESD Sensitivity (HBM)	Class 1A

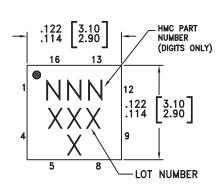
#### **Truth Table**

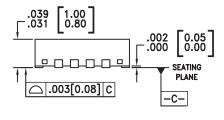
Control Input		Signal Path State
Α	В	RFCOM to:
High	High	RF1
Low	High	RF2
High	Low	RF3
Low	Low	RF4



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

# **Outline Drawing**





# BOTTOM VIEW .012 [0.30] PIN 16 .008 [0.20] MIN .061 [1.56] .057 [1.44] .022 [0.56] .017 [0.44] .059 [1.50] .059 EXPOSED GROUND PADDLE MUST BE CONNECTED TO RF/DC GROUND SQUARE

#### NOTES:

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS].
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED PCB LAND PATTERN.

## Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC344LP3	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	344 XXXX
HMC344LP3E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	344 XXXX

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





# GaAs MMIC SP4T NON-REFLECTIVE SWITCH, DC - 8.0 GHz

# **Pin Descriptions**

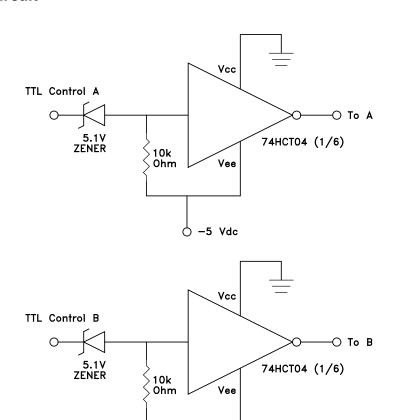
Pin Number	Function	Description	Interface Schematic
1, 4, 9, 12, 15	RF4, RF3, RF2, RF1, RFC	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required if RF line potential is not equal to 0V.	
2, 3, 10, 11, 13	N/C	This pin should be connected to PCB RF ground to maximize isolation.	GND =
5, 14, 16	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	⊖ GND
6	VEE	Supply Voltage -5V ± 10%	VEE 0 5pF 2K = =
7	CTLB	See truth table and control voltage table.	100K
8	CTLA	See truth table and control voltage table.	VEE =





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## **TTL Interface Circuit**

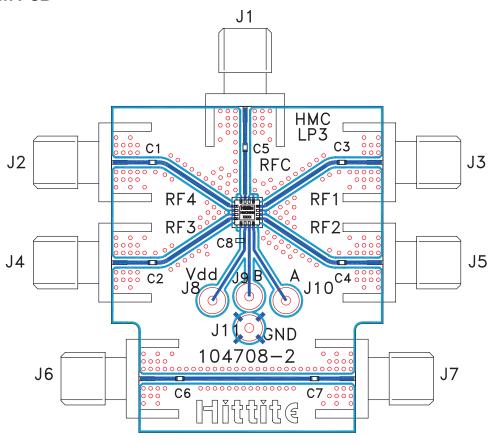






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#### **Evaluation PCB**



## List of Materials for Evaluation PCB 105311 [1]

Item	Description	
J1 - J7	PCB Mount SMA RF Connector	
J8 - J11	DC Pin	
C1 - C7	100 pF Capacitor, 0402 Pkg.	
C8	10k pF Capacitor, 0603 Pkg.	
U1	HMC344LP3 / HMC344LP3E SP4T Switch	
PCB [2]	104708 Evaluation PCB 1.29"x1.55"	

<sup>[1]</sup> Reference this number when ordering complete evaluation PCB  $\,$ 

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.

<sup>[2]</sup> Circuit Board Material: Rogers 4350